

STTH3R06

TURBO 2 ULTRAFAST HIGH VOLTAGE RECTIFIER

Table 1: Main Product Characteristics

I _{F(AV)}	3 A
V _{RRM}	600 V
I _R (max)	100 μΑ
T _j	175°C
V _F (typ)	1.0 V
t _{rr} (typ)	35 ns

FEATURES AND BENEFITS

- Ultrafast switching
- Low forward voltage drop
- Low thermal resistance
- Low leakage current (platinium doping)

DESCRIPTION

The STTH3R06, which is using ST Turbo 2 600V technology, is specially suited for use in switching power supplies, inverters and as a free wheeling diode.

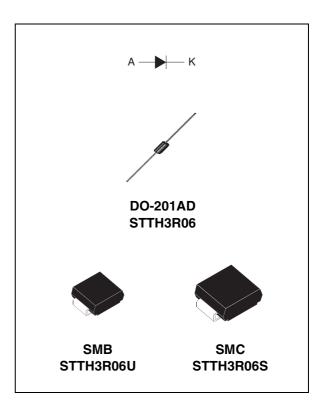


Table 2: Order Codes

Part Number	Marking
STTH3R06	STTH3R06
STTH3R06RL	STTH3R06
STTH3R06U	3R6U
STTH3R06S	R6S

Table 3: Absolute Ratings (limiting values)

Symbol	Paramet	Value	Unit		
V_{RRM}	Repetitive peak reverse voltage			600	V
I _{F(RMS)}	RMS forward current	RMS forward current			
I _{F(AV)}	Average forward current	verage forward current DO-201AD TI = 80°C			
	$\delta = 0.5$	SMB $TI = 55^{\circ}C$			
I _{FSM}	Surge non repetitive forward current	DO-201AD	tp = 10ms	55	Α
		45			
T _{stg}	Storage temperature range			-65 to + 175	°C
T _j	Maximum operating junction temperature			175	°C

Table 4: Thermal Parameters

Symbol	Paramete	Parameter		
R _{th(j-l)}	Junction to lead	DO-201AD L = 10 mm	20	°C/W
		SMB	25	
		SMC	20	
R _{th(j-a)}	Junction to ambient (see fig. 13)	DO-201AD L = 10 mm	75	°C/W

Table 5: Static Electrical Characteristics

Symbol	Parameter	Test conditions		Min.	Тур	Max.	Unit
I _R	Reverse leakage current	T _j = 25°C	$V_R = V_{RRM}$			3	μΑ
		T _j = 150°C			15	100	
V _F	Forward voltage drop	$T_j = 25^{\circ}C$	I _F = 3A			1.7	V
		T _j = 150°C			1.0	1.25	

To evaluate the conduction losses use the following equation: $P = 1.03 \times I_{F(AV)} + 0.09 I_{F}^{2}$ (RMS)

Table 6: Dynamic Characteristics

Symbol	Parameter	Test conditions			Тур	Max.	Unit
t _{rr}		T _j = 25°C	I _F = 0.5A I _{RR} = 0.25A I _R = 1A			30	ns
	time		$I_F = 1A dI_F/dt = -50 A/\mu s V_R = 30V$		35		
t _{fr}	Forward recovery time	T _j = 25°C	$I_F = 3A$ $dI_F/dt = 100 A/\mu s$ $V_{FR} = 1.1 \times V_{Fmax}$			100	ns
V _{FP}	Forward recovery voltage		$I_F = 3A$ $dI_F/dt = 100 A/\mu s$			10	V

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Figure 1: Conduction losses versus average current

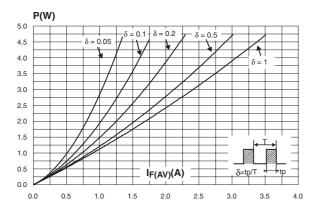


Figure 3: Relative variation of thermal impedance junction ambient versus pulse duration (epoxy printed circuit FR4, $L_{leads} = 10$ mm, $S_{CU}=1$ cm²)

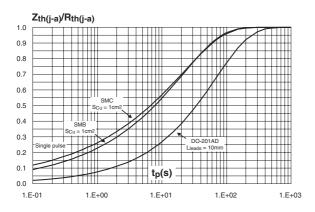


Figure 5: Reverse recovery time versus dI_F/dt (typical values)

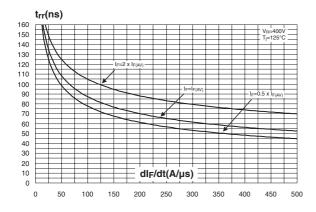


Figure 2: Forward voltage drop versus forward current

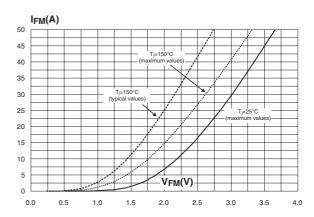


Figure 4: Peak reverse recovery current versus dI_F/dt (typical values)

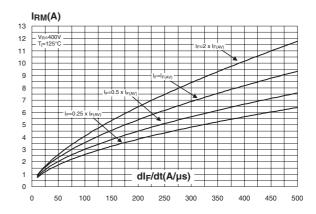


Figure 6: Reverse recovery charges versus dl_F/dt (typical values)

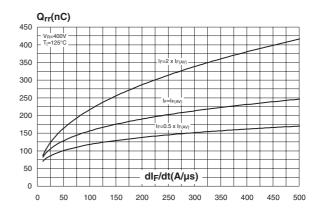


Figure 7: Softness factor versus d_{IF}/dt (typical values)

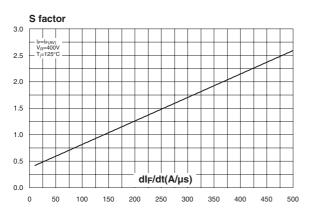


Figure 9: Transient peak forward voltage versus dl_F/dt (typical values)

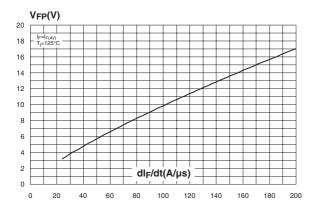


Figure 11: Junction capacitance versus reverse voltage applied (typical values)

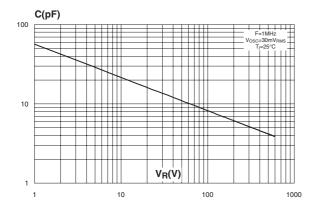


Figure 8: Relative variations of dynamic parameters versus junction temperature

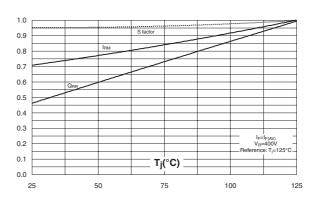


Figure 10: Forward recovery time versus dI_F/dt (typical values)

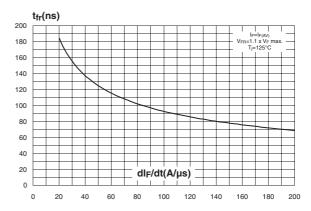
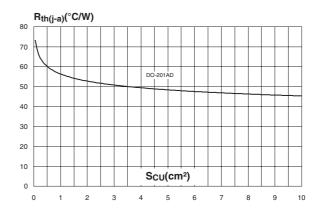


Figure 12: Thermal resistance junction to ambient versus copper surface under lead (epoxy FR4, e_{CU}=35µm) (DO-201AD)



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Figure 13: Thermal resistance junction to ambient versus copper surface under lead (epoxy FR4, e_{CU} =35 μ m) (SMB / SMC)

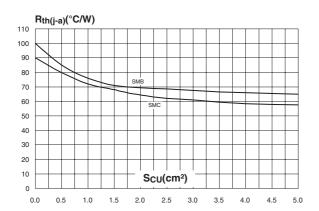


Figure 14: Thermal resistance versus lead length

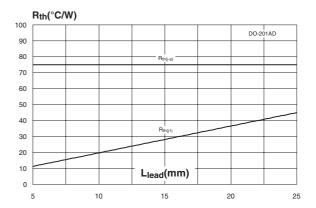
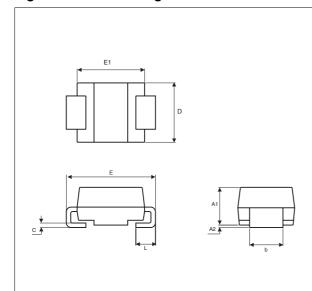
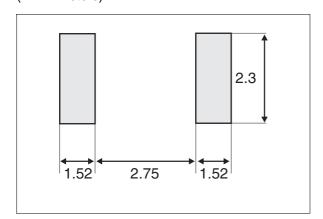


Figure 15: SMB Package Mechanical Data



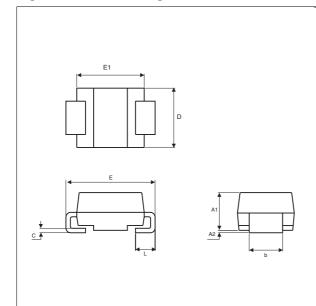
	DIMENSIONS				
REF.	Millin	neters	Inc	hes	
	Min.	Max.	Min.	Max.	
A1	1.90	2.45	0.075	0.096	
A2	0.05	0.20	0.002	0.008	
b	1.95	2.20	0.077	0.087	
С	0.15	0.41	0.006	0.016	
Е	5.10	5.60	0.201	0.220	
E1	4.05	4.60	0.159	0.181	
D	3.30	3.95	0.130	0.156	
L	0.75	1.60	0.030	0.063	

Figure 16: SMB Foot Print Dimensions (in millimeters)



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Figure 17: SMC Package Mechanical Data



	DIMENSIONS				
REF.	Millin	neters	Inc	hes	
	Min.	Max.	Min.	Max.	
A1	1.90	2.45	0.075	0.096	
A2	0.05	0.20	0.002	0.008	
b	2.90	3.2	0.114	0.126	
С	0.15	0.41	0.006	0.016	
Е	7.75	8.15	0.305	0.321	
E1	6.60	7.15	0.260	0.281	
E2	4.40	4.70	0.173	0.185	
D	5.55	6.25	0.218	0.246	
L	0.75	1.60	0.030	0.063	

Figure 18: SMC Foot Print Dimensions (in millimeters)

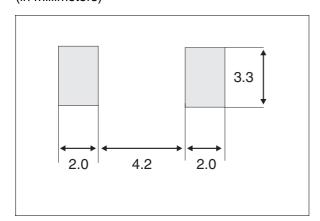
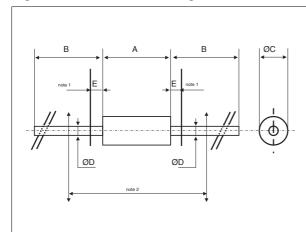


Figure 19: DO-201AD Package Mechanical Data



		ISIONS		
REF.	Millim	neters	Inc	hes
	Min.	Max.	Min.	Max.
Α		9.50		0.374
В	25.40		1.000	
С		5.30		0.209
D		1.30		0.051
Е		1.25		0.049
		1 - The lead diameter ø D is not controlled over zone E 2 - The minimum axial length within which the device		

2 - The minimum axial length within which the device may be placed with its leads bent at right angles is 0.59"(15 mm)

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

Table 7: Ordering Information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STTH3R06	STTH3R06	DO-201AD	1.12 g	600	Ammopack
STTH3R06-RL	STTH3R06	DO-201AD	1.12 g	1900	Tape & reel
STTH3R06U	3R6U	SMB	0.11 g	2500	Tape & reel
STTH3R06S	R6S	SMC	0.243 g	2500	Tape & reel

- Epoxy meets UL94, V0
- Band indicated cathode (DO-201AD)
- Bending method: see application note AN1471 (DO-201AD)

Table 8: Revision History

Date	Revision	Description of Changes
March-2003	1	First issue
07-Sep-2004	2	SMB and SMC packages added
14-Oct-2005	3	Changed marking of STTH3R06U from R06U to 3R6U on page 1. Added ECOPACK statement.

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